

PNP Silicon Epitaxial Transistor

PZT2907A

This PNP Silicon Epitaxial transistor is designed for use in linear and switching applications. The device is housed in the SOT-223 package which is designed for medium power surface mount applications.

Features

- NPN Complement is PZT2222AT1
- The SOT-223 Package can be Soldered Using Wave or Reflow
- SOT-223 Package Ensures Level Mounting, Resulting in Improved Thermal Conduction, and Allows Visual Inspection of Soldered Joints. The Formed Leads Absorb Thermal Stress during Soldering Eliminating the Possibility of Damage to the Die
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and **PPAP** Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V_{CEO}	-60	Vdc
Collector - Base Voltage	V_{CBO}	-60	Vdc
Emitter - Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current - Continuous	I _C	-600	mAdc

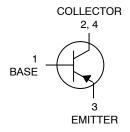
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

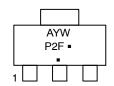
Characteristic	Symbol	Max	Unit
Total Device Dissipation (Note 1) $T_A = 25^{\circ}C$	P _D	1.5 12	W mW/°C
Thermal Resistance Junction-to-Ambient (Note 1)	$R_{\theta JA}$	83.3	°C/W
Lead Temperature for Soldering, 0.0625" from case Time in Solder Bath	TL	260 10	°C Sec
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

^{1.} FR-4 with 1 oz and 713 mm² of copper area.





MARKING DIAGRAM



P2F = Specific Device Code Α = Assembly Location

Υ = Year W = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
PZT2907AT1G	SOT-223 (Pb-Free)	1,000 / Tape & Reel
SPZT2907AT1G	SOT-223 (Pb-Free)	1,000 / Tape & Reel
PZT2907AT3G	SOT-223 (Pb-Free)	4,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

С	haracteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•		•	•	
Collector-Base Breakdown Vo	ltage	V _{(BR)CBO}	-60	_	-	Vdc
Collector–Emitter Breakdown Voltage ($I_C = 10 \text{ mAdc}, I_B = 0$)		V _{(BR)CEO}	-60	_	-	Vdc
Emitter-Base Breakdown Volta $(I_E = -10 \mu Adc, I_C = 0)$	age	V _{(BR)EBO}	-5.0	_	-	Vdc
Collector-Base Cutoff Current $(V_{CB} = -50 \text{ Vdc}, I_E = 0)$		I _{CBO}	-	-	-10	nAdc
Collector-Emitter Cutoff Curre (V _{CE} = -30 Vdc, V _{BE} = 0.5 V		I _{CEX}	-	-	-50	nAdc
Base-Emitter Cutoff Current (V _{CE} = -30 Vdc, V _{BE} = -0.5	Vdc)	I _{BEX}	-	_	-50	nAdc
ON CHARACTERISTICS (Note 2)			•	•	
DC Current Gain	Vdc) /dc) · Vdc)	h _{FE}	75 100 100 100 50	- - - -	- - 300 -	-
Collector-Emitter Saturation Vo ($I_C = -150$ mAdc, $I_B = -15$ m ($I_C = -500$ mAdc, $I_B = -50$	nAdc)	V _{CE(sat)}	- -	- -	-0.4 -1.6	Vdc
Base-Emitter Saturation Voltage ($I_C = -150 \text{ mAdc}$, $I_B = -15 \text{ m}$) ($I_C = -500 \text{ mAdc}$, $I_B = -50 \text{ m}$)	nAdc)	V _{BE(sat)}	- -	- -	-1.3 -2.6	Vdc
DYNAMIC CHARACTERIS	TICS			•	•	
Current-Gain – Bandwidth Pro (I _C = -50 mAdc, V _{CE} = -20		f _T	200	_	_	MHz
Output Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1	.0 MHz)	C _c	-	-	8.0	pF
Input Capacitance (V _{EB} = -2.0 Vdc, I _C = 0, f =	1.0 MHz)	C _e	-	-	30	pF
SWITCHING TIMES						
Turn-On Time		t _{on}	-	-	45	ns
Delay Time	$(V_{CC} = -30 \text{ Vdc}, I_{C} = -150 \text{ mAdc}, I_{B1} = -15 \text{ mAdc})$	t _d	-	-	10	
Rise Time		t _r	-	-	40	
Turn-Off Time		t _{off}	-	-	100	ns
Storage Time	$(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -150 \text{ mAdc}, I_{B_1} = I_{B_2} = -15 \text{ mAdc})$	t _s	-	-	80	
Fall Time		t _f	-	-	30	

^{2.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

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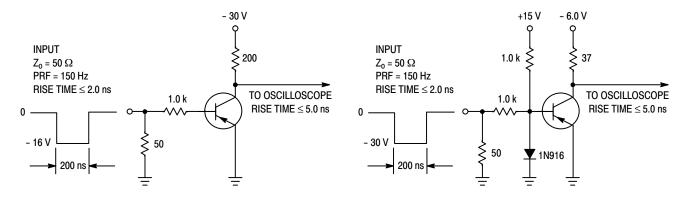


Figure 1. Delay and Rise **Time Test Circuit**

Figure 2. Storage and Fall **Time Test Circuit**

TYPICAL ELECTRICAL CHARACTERISTICS

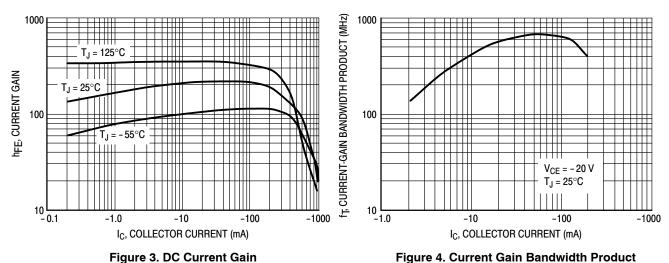


Figure 3. DC Current Gain

-1.0 30 $T_J = 25^{\circ}C$ 20 -0.8 $V_{BE(sat)} @ I_C/I_B = 10$ CAPACITANCE (pF) VOLTAGE (VOLTS) V_{BE(on)} @ V_{CE} = -10 V 10 7.0 \mathbf{C}_{cb} 5.0 -0.2 3.0 $V_{CE(sat)} @ I_C/I_B = 10$ -0.1 -0.2 -0.5 -1.0 -2.0 -5.0 -10 -20 -50 -100 -200 -0.2 -0.3 -0.5 -0.7 -1.0 -2.0 -3.0 -5.0 -7.0 -10 -20 -30 I_C, COLLECTOR CURRENT (mA) REVERSE VOLTAGE (VOLTS)

Figure 5. "ON" Voltage

Figure 6. Capacitances

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